

PS2715-1

HIGH CTR, AC INPUT 4-PIN SOP PHOTOCOUPLER

R08DS0161EJ0100 Rev.1.00 Jun 13, 2019

DESCRIPTION

The PS2715-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor in a plastic SOP for high density applications.

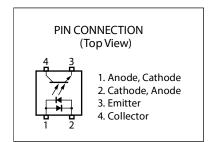
The package is an SOP (Small Outline Package) type for high density mounting applications.

FEATURES

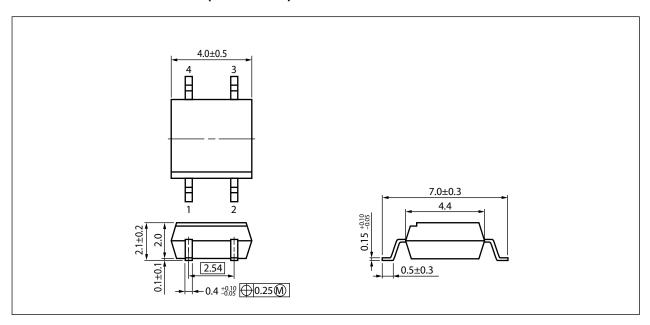
- AC input response
- High current transfer ratio (CTR = 200% TYP. @ $I_F = \pm 1$ mA)
- High isolation voltage (BV = 3 750 Vr.m.s.)
- Small and thin package (4-pin SOP)
- Ordering number of taping product: PS2715-1-F3: 3 500 pcs/reel
- Pb-Free product
- · Safety standards
 - UL approved: UL1577, Single protection
 - CSA approved: CAN/CSA-C22.2 No. 62368-1, Basic/Supplementary insulation
 - VDE approved: DIN EN 60747-5-5 (Option)

APPLICATIONS

- Programmable logic controllers
- Modem/FAX



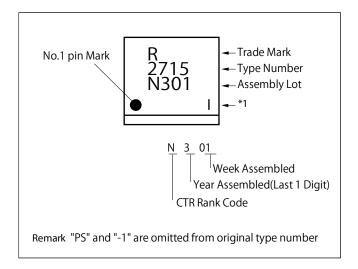
PACKAGE DIMENSIONS (UNIT: mm)



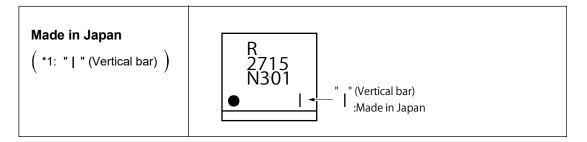
PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	5 mm
Creepage Distance	5 mm
Isolation Distance	0.3 mm

MARKING EXAMPLE



Note: Bar indication contents of *1.



ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS2715-1-F3	PS2715-1-F3-A	Pb-Free	Embossed Tape 3 500 pcs/reel	Standard products (UL, CSA, approved)	PS2715-1
PS2715-1-V-F3	PS2715-1-V-F3-A		Embossed Tape 3 500 pcs/reel	UL, CSA, DIN EN 60747-5-5 approved	

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	±50	mA
	Power Dissipation Derating	⊿P _D /°C	0.8	mW/°C
	Power Dissipation	PD	80	mW
	Peak Forward Current*1	IFP	±0.5	Α
Transistor	Collector to Emitter Voltage	V _{CEO}	40	V
	Emitter to Collector Voltage	V _E CO	5	V
	Collector Current	Ic	40	mA
	Power Dissipation Derating	⊿Pc/°C	1.5	mW/°C
	Power Dissipation	Pc	150	mW
Isolation Voltage*2		BV	3 750	Vr.m.s.
Operating Ambient Temperature		TA	-55 to +100	°C
Storage Temperature		T _{stg}	-55 to +150	°C

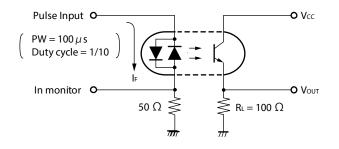
Note: *1. PW = 100 μ s, Duty Cycle = 1%

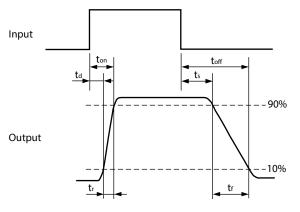
^{*2.} AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V _F	I _F = ±5 mA		1.15	1.4	V
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		60		pF
Transistor	Collector to Emitter Dark Current	I _{CEO}	I _F = 0 mA, V _{CE} = 40 V			100	nA
Coupled	Current Transfer Ratio (I _C /I _F)	CTR	I _F = ±1 mA, V _{CE} = 5 V	100	200	400	%
	Collector Saturation Voltage	V _{CE (sat)}	$I_F = \pm 1 \text{ mA}, I_C = 0.2 \text{ mA}$			0.3	V
	Isolation Resistance	R _{I-O}	V _{I-O} = 1.0 kV _{DC}	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.4		pF
	Rise Time*1	tr	V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω		4		μS
	Fall Time*1	t _f			5		

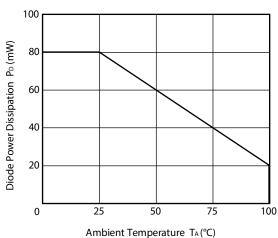
Note: *1. Test Circuit for Switching Time



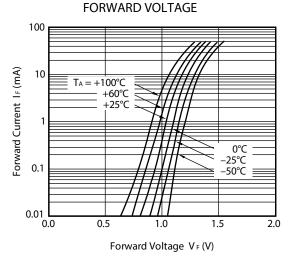


TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

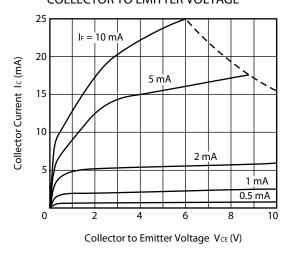




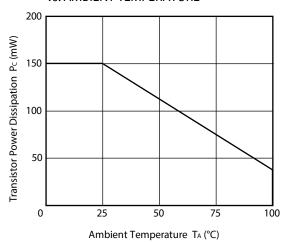
FORWARD CURRENT vs.



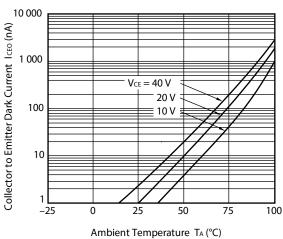
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



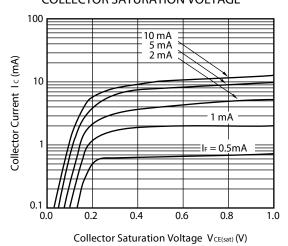
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



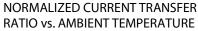
COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE

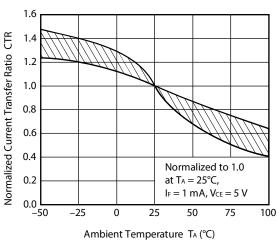


COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE

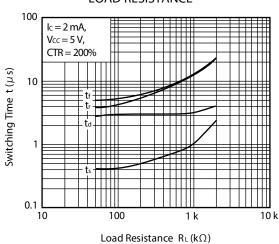


Remark The graphs indicate nominal characteristics.

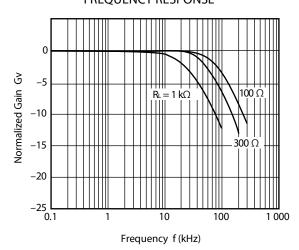




SWITCHING TIME vs. LOAD RESISTANCE

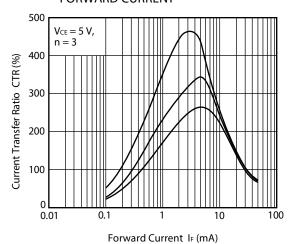


FREQUENCY RESPONSE



Remark The graphs indicate nominal characteristics.

CURRENT TRANSFER RATIO vs. FORWARD CURRENT



SWITCHING TIME vs.

1k

0.1

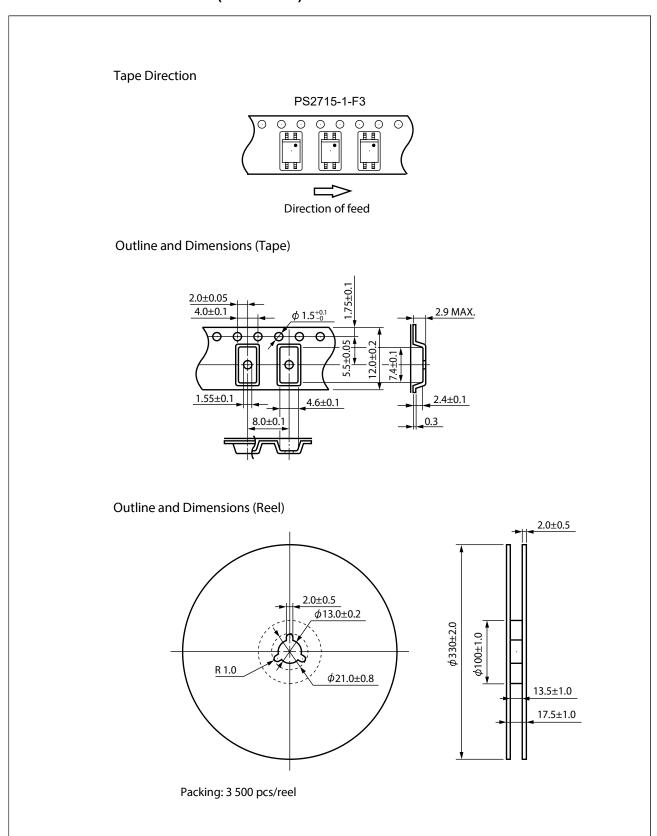
100

Load Resistance R_L (Ω)

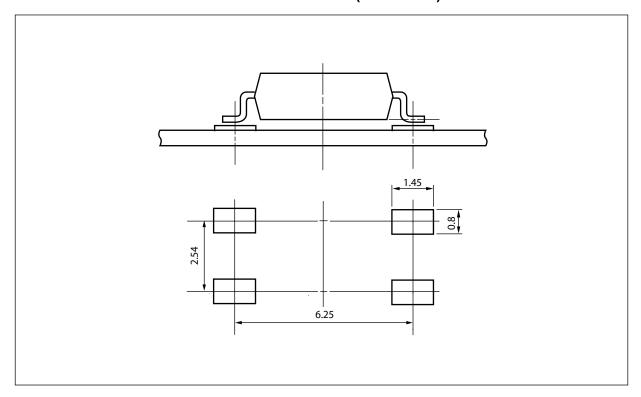
10 k

100 k

TAPING SPECIFICATIONS (UNIT: mm)



RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



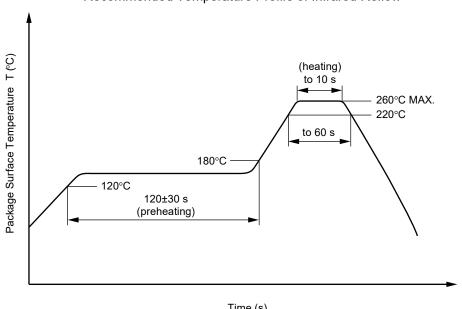
Remark All dimensions in this figure must be evaluated before use.

NOTES ON HANDLING

- 1. Recommended soldering conditions
 - (1) Infrared reflow soldering
 - Peak reflow temperature 260°C or below (package surface temperature)
 - · Time of peak reflow temperature 10 seconds or less Time of temperature higher than 220°C
 - Time to preheat temperature from 120 to 180°C
 - Number of reflows
 - Flux

- 60 seconds or less
- 120±30 s
- Three Rosin flux containing small amount of chlorine
- (The flux with a maximum chlorine content of
- 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

 Temperature 260°C or below (molten solder temperature)

 Time 10 seconds or less

 Preheating conditions 120°C or below (package surface temperature)

 Number of times One (Allowed to be dipped in solder including plastic mold portion.) Rosin flux containing small amount of chlorine (The flux with a maximum • Flux

chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

 Peak Temperature (lead part temperature) 350°C or below Time (each pins) 3 seconds or less

• Flux Rosin flux containing small amount of chlorine

(The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

Flux Cleaning

Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.

• Do not use fixing agents or coatings containing halogen-based substances.

- 2. Cautions regarding noise
 - Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.
- Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

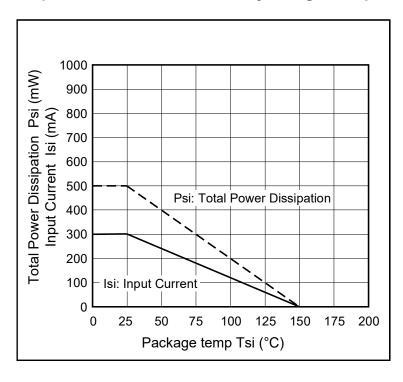
USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.

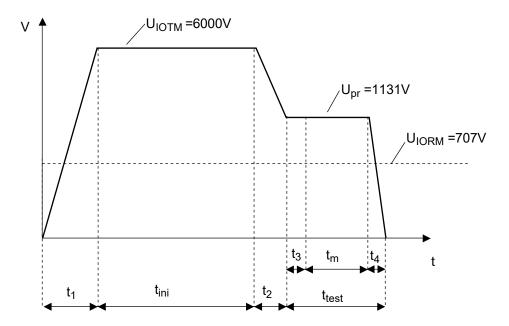
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength			
maximum operating isolation voltage	U _{IORM}	707	V_{peak}
Test voltage (partial discharge test, procedure a for type test and	U_pr	1 131	V _{peak}
random test)			
Upr = $1.6 \times U_{IORM}$, $P_d < 5 pC$			
Test voltage (partial discharge test, procedure b for all devices)	Upr	1 325	V_{peak}
$U_{pr} = 1.875 \times U_{IORM}, P_d < 5 pC$			
Highest permissible overvoltage	U _{IOTM}	6 000	V_{peak}
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	CTI	175	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		III a	
Storage temperature range	T _{stg}	-55 to +150	°C
Operating temperature range	TA	-55 to +100	°C
Isolation resistance, minimum value			
V _{IO} = 500 V dc at T _A = 25°C	Ris MIN.	10 ¹²	Ω
V _{IO} = 500 V dc at T _A MAX. at least 100°C	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see			
thermal derating curve)			
Package temperature	Tsi	150	°C
Current (input current I _F , Psi = 0)	Isi	300	mA
Power (output or total power dissipation)	Psi	500	mW
Isolation resistance		_	
$V_{IO} = 500 \text{ V dc at } T_A = Tsi$	Ris MIN.	10 ⁹	Ω

Dependence of maximum safety ratings with package temperature



Method a) Destructive Test, Type and Sample Test



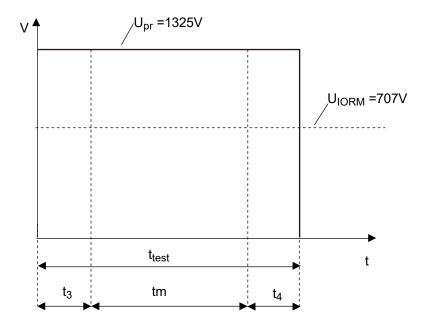
 $t_1, t_2 = 1 \text{ to } 10 \text{ sec}$

 $t_3, t_4 = 1 \text{ sec}$

 $t_{m(PARTIAL\ DISCHARGE)}$ = 10 sec t_{test} = 12 sec

 t_{ini} = 60 sec

Method b) Non-destructive Test, 100% Production Test



 $t_3, t_4 = 0.1 \text{ sec}$

 $t_{\text{m(PARTIAL DISCHARGE)}}$ = 1.0 sec t_{test} = 1.2 sec

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or i any way allow it to enter the mouth.

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